Features

- Current-controlled Output Current Source with 3 Input Channels
- Two Selectable Outputs for Grounded Laser Diodes
- Output Current per Write Channel: 350 mA
- Total Output Current: 500 mA
- 500 Ω Channel Input Resistance
- On-chip RF Oscillator
- Control of Two Different Swings by Use of Two External Resistors
- Oscillator Frequency Range from 200 MHz to 500 MHz
- Oscillator Swing: 100 mA
- Single 5 V Power Supply
- Common Enable/Disable Input
- TTL/CMOS Control Signals
- Small Pb-free QFN16 (4 mm x 4 mm) or SSO16 Package

Applications

- DVD-ROM with CD-RW Capability
- DVD+RW with CD-RW Capability
- DVD-RW with CD-RW Capability
- Writable Optical Drives

Description

The ATR0807 is a laser diode driver for the operation of two different grounded laser diodes for DVD-RW/DVD+RW (650 nm) and CD-RW (780 nm). It includes three channels for three different optical power levels which are controlled by a separate IC. The read channel generates a continuous output level, whereas the channels 2 and 3 are provided as write channels with very fast switching speeds. Write current pulses are enabled when a low signal is applied to the NE pins. All channels are summed together and switched to one of the two IOUTA or IOUTB outputs by the select input SELA. Each write channel (channel 2 and 3) can contribute up to 350 mA to the total output current, up to 500 mA. The read channel can contribute up to 150 mA. Total gains of 100 (read channel), 250 (channel 2 and 3) are provided between each reference current input and the selected output. Although, the reference inputs are current inputs, voltage control is possible by using external resistors. An on-chip RF oscillator is provided to reduce laser mode hopping noise during read mode. Swing can be set independently for the two selectable outputs with two different resistors. Oscillation is enabled by a high signal at the ENOSC pin. Complete output current and oscillator switch-off is achieved by a low signal at the ENABLE input.



Three Channel Laser Driver with RF Oscillator and Two Outputs

ATR0807

(Summary)

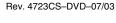
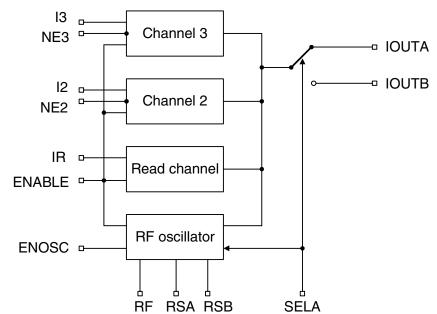




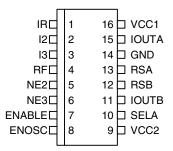


Figure 1. Block Diagram



Pin Configuration SSO16

Figure 2. Pinning SSO16



Pin Description

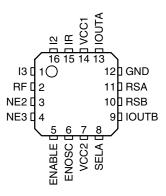
Pin	Symbol	Туре	Function	
1	IR	Analog	Input current, bias voltage approximately GND	
2	12	Analog	Input current, bias voltage approximately GND	
3	13	Analog	Input current, bias voltage approximately GND	
4	RF	Analog	External resistor to GND sets frequency of oscillator	
5	NE2	Digital	Digital control of channel 2 (low active)	
6	NE3	Digital	Digital control of channel 3 (low active)	
7	ENABLE	Digital	Enables output current (high active)	
8	ENOSC	Digital	Enables RF oscillator (high active)	
9	VCC2	Supply	+5 V power supply for IOUT	
10	SELA	Digital	High: selects IOUTA, RSA Low: selects IOUTB, RSB	
11	IOUTB	Analog	Output current source B for laser diode	
12	RSB	Analog	External resistor to GND sets swing of oscillator B	
13	RSA	Analog	External resistor to GND sets swing of oscillator A	
14	GND	Supply	Ground	
15	IOUTA	Analog	Output current source A for laser diode	
16	VCC1	Supply	+5 V power supply for IOUT and circuit	





Pin Configuration QFN16

Figure 3. Pinning QFN16



Pin Description

Pin	Symbol	Туре	Function	
1	13	Analog	Input current, bias voltage approximately GND	
2	RF	Analog	External resistor to GND sets frequency of oscillator	
3	NE2	Digital	Digital control of channel 2 (low active)	
4	NE3	Digital	Digital control of channel 3 (low active)	
5	ENABLE	Digital	Enables output current (high active)	
6	ENOSC	Digital	Enables RF oscillator (high active)	
7	VCC2	Supply	+5 V power supply for IOUT	
8	SELA	Digital	High: selects IOUTA, RSA Low: selects IOUTB, RSB	
9	IOUTB	Analog	Output current source B for laser diode	
10	RSB	Analog	External resistor to GND sets swing of oscillator B	
11	RSA	Analog	External resistor to GND sets swing of oscillator A	
12	GND	Supply	Ground	
13	IOUTA	Analog	Output current source A for laser diode	
14	VCC1	Supply	+5 V power supply for circuit	
15	IR	Analog	Input current, bias voltage approximately GND	
16	12	Analog	Input current, bias voltage approximately GND	
Paddle	GND	Supply	Ground	

Absolute Maximum Ratings

Parameters	Symbol	Value	Unit
Supply voltage	V _{CC}	-0.5 to +6.0	V
Input voltage at any input	V _{in}	-0.5 to V _{CC} +0.5	V
Power dissipation	P _{max}	0.7 ⁽¹⁾ to 1 ⁽²⁾	W
Output voltage	V _{out}	-0.5 to V _{CC} -1	V
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-65 to +125	°C

Notes: 1. $R_{thJA} \le 115$ K/W at $T_{amb} = 70$ °C 2. $R_{thJA} \le 115$ K/W at $T_{amb} = 25$ °C

Thermal Resistance

Parameters	Symbol	Value	Unit
Junction ambient	R_{thJA}	115 ⁽¹⁾	K/W

Notes: 1. Measured with multi-layer test board (JEDEC standard)

Recommended Operating Conditions

Parameters	Symbol	Value	Unit
Supply voltage	V _{CC}	4.5 to 5.5	V
Input current	I _{IR} , I _{I2} , I _{I3}	I _{IR} < 2.0, I _{I2} = I _{I3} < 1.5	mA
External resistor to GND to set oscillator frequency	RF	> 3	kΩ
External resistor to GND to set oscillator swing	RSA, RSB	> 1	kΩ
Operating temperature range	T _{amb}	0 to +70	°C

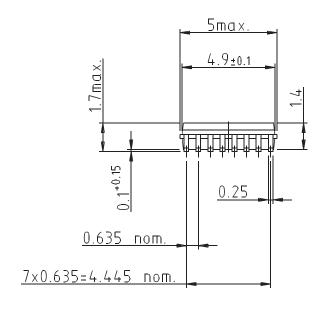


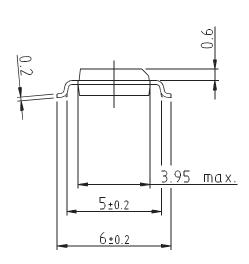


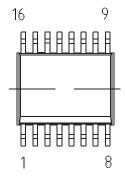
Ordering Information

Extended Type Number	Package	Remarks
ATR0807-TCQ	Pb-free SSO16	Taped and reeled
ATR0807-PEQ	Pb-free QFN16 (4 mm x 4 mm)	Taped and reeled

Package SSO16









Drawing refers to following types: SS016

Package acc. JEDEC MO 137 AB

Drawing-No.: 6.543-5060.01-4

Issue: 2; 05.02.99

Package QFN16 (4 mm x 4 mm)

Package: QFN 16 - 4x4 Exposed pad 2.1x2.1

(acc. JEDEC OUTLINE No. MO-220)

Dimensions in mm

Drawing-No.: 6.543-5090.01-4

Issue 2, 24.01.03





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